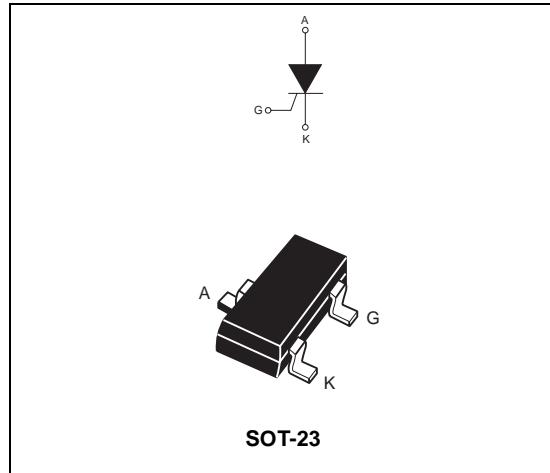


SENSITIVE
0.25A SCRs
MAIN FEATURES:

Symbol	Value	Unit
$I_{T(RMS)}$	0.25	A
V_{DRM}/V_{RRM}	200	V
I_{GT}	200	μA


DESCRIPTION

Thanks to highly sensitive triggering levels, the P0102BL SCR is suitable for all applications where the available gate current is limited such as stand-by mode power supplies, smoke and alarm detectors...

Available in SOT-23, it provides optimized space saving on high density printed circuit boards.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state current (180° conduction angle)	$T_{amb} = 30^\circ C$	0.25	A
$I_{T(AV)}$	Average on-state current (180° conduction angle)	$T_{amb} = 30^\circ C$	0.17	A
I_{TSM}	Non repetitive surge peak on-state current	$t_p = 8.3 \text{ ms}$	7	A
		$t_p = 10 \text{ ms}$		
I^2t	I^2t Value for fusing	$t_p = 10 \text{ ms}$	$T_j = 25^\circ C$	$A^2\text{s}$
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}, t_r \leq 100\text{ns}$	$F = 60 \text{ Hz}$	$T_j = 125^\circ C$	$A/\mu s$
I_{GM}	Peak gate current	$t_p = 20 \mu s$	$T_j = 125^\circ C$	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 125^\circ C$	W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range		- 40 to + 150 - 40 to + 125	°C

ELECTRICAL CHARACTERISTICS ($T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Test Conditions		P0102BL	Unit	
I_{GT}	$V_D = 12 \text{ V}$ $R_L = 140 \Omega$	MAX.	200	μA	
V_{GT}		MAX.	0.8	V	
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $R_{GK} = 1 \text{ k}\Omega$	$T_j = 125^\circ\text{C}$	MIN.	0.1	V
V_{RG}	$I_{RG} = 10 \mu\text{A}$		MIN.	8	V
I_H	$I_T = 50 \text{ mA}$ $R_{GK} = 1\text{k}\Omega$		MAX.	6	mA
I_L	$I_G = 1 \text{ mA}$ $R_{GK} = 1\text{k}\Omega$		MAX.	7	mA
dV/dt	$V_D = 67\% V_{DRM}$ $R_{GK} = 1\text{k}\Omega$	$T_j = 125^\circ\text{C}$	MIN.	200	V/ μs
V_{TM}	$I_{TM} = 0.4 \text{ A}$ $t_p = 380 \mu\text{s}$	$T_j = 25^\circ\text{C}$	MAX.	1.7	V
V_{t0}	Threshold voltage	$T_j = 125^\circ\text{C}$	MAX.	1.0	V
R_d	Dynamic resistance	$T_j = 125^\circ\text{C}$	MAX.	1000	$\text{m}\Omega$
I_{DRM}	$V_{DRM} = V_{RRM}$	$T_j = 25^\circ\text{C}$	MAX.	1	μA
I_{RRM}		$T_j = 125^\circ\text{C}$		100	

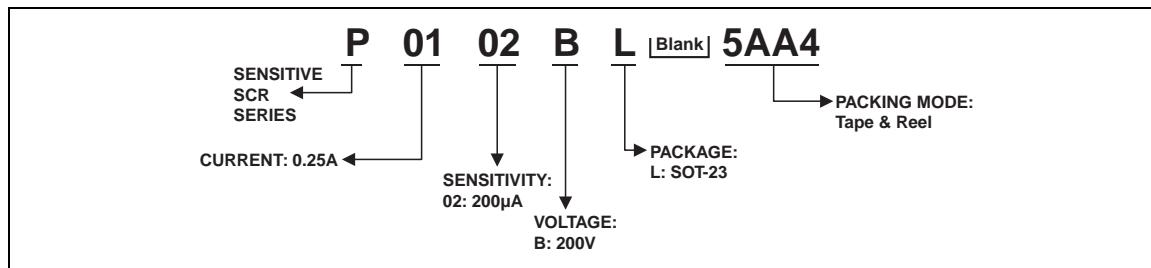
THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction to ambient (mounted on FR4 with recommended pad layout)	400	$^\circ\text{C/W}$

PRODUCT SELECTOR

Part Number	Voltage	Sensitivity	Package
P0102BL	200 V	200 μA	SOT-23

ORDERING INFORMATION



OTHER INFORMATION

Part Number	Marking	Weight	Base quantity	Packing mode
P0102BL	P2B	0.01 g	3000	Tape & reel

Fig. 1: Maximum average power dissipation versus average on-state current.

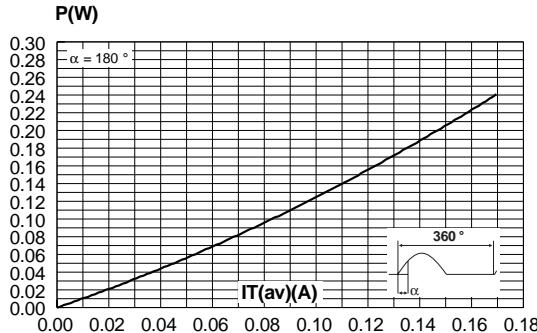


Fig. 3: Relative variation of thermal impedance junction to ambient versus pulse duration.

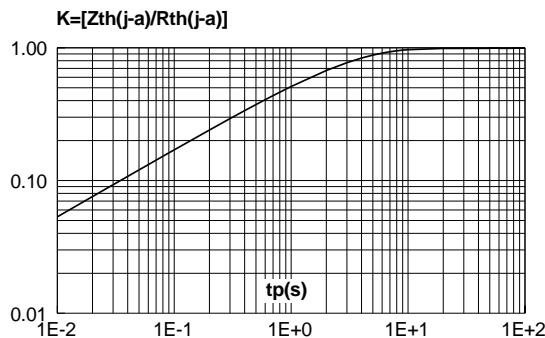


Fig. 5: Relative variation of holding current versus gate-cathode resistance (typical values).

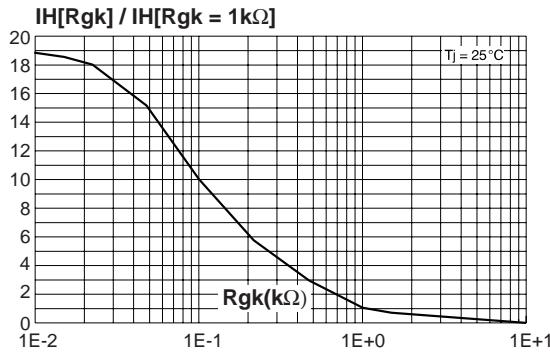


Fig. 2: Average and D.C. on-state current versus ambient temperature.

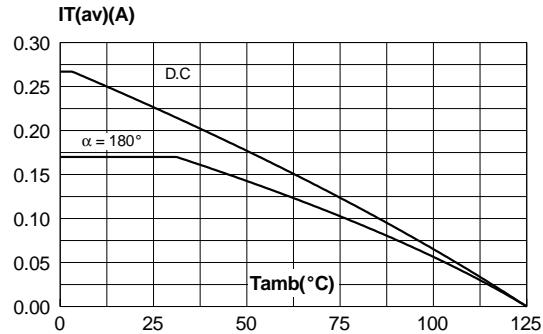


Fig. 4: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).

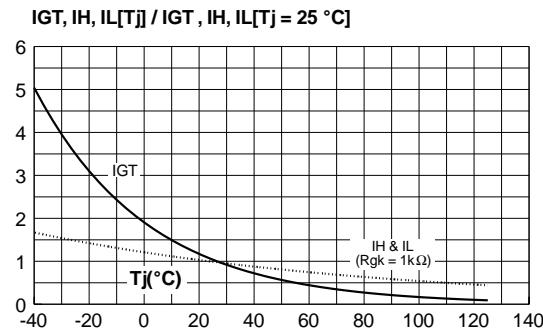


Fig. 6: Relative variation of dV/dt immunity versus gate-cathode resistance (typical values).

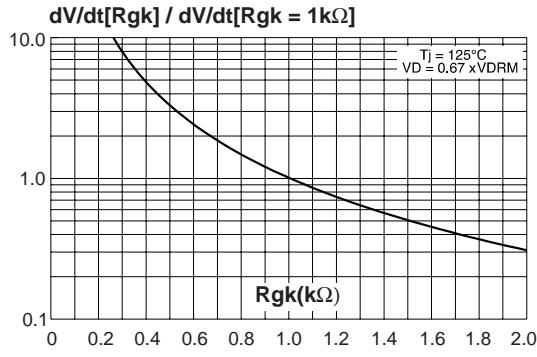


Fig. 7: Relative variation of dV/dt immunity versus gate-cathode capacitance (typical values).

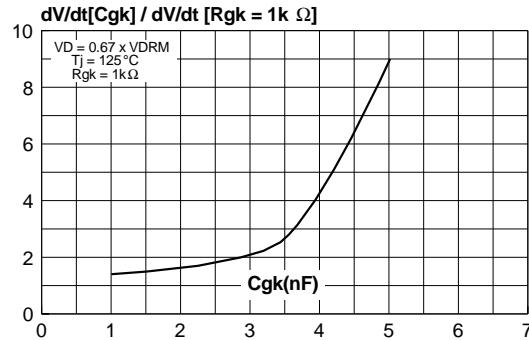


Fig. 9: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $tp < 10ms$, and corresponding value of I^2t .

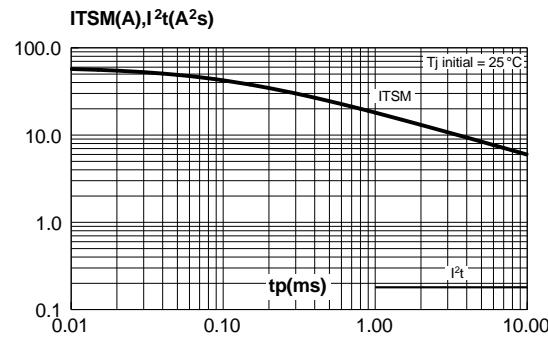


Fig. 11: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: 35 μm).

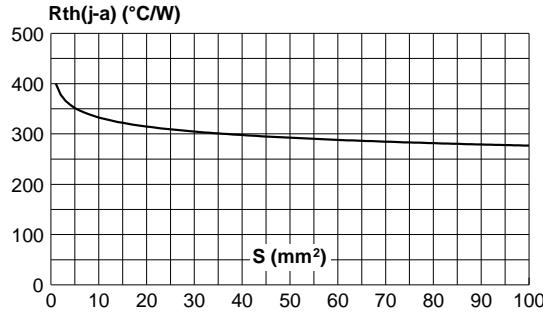


Fig. 8: Surge peak on-state current versus number of cycles.

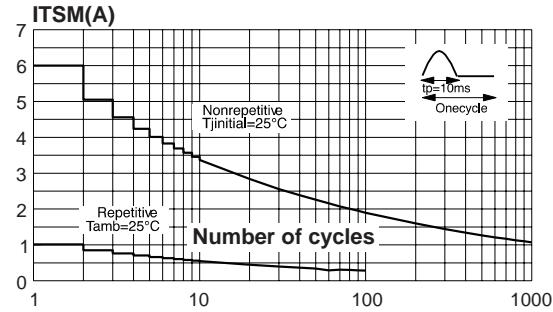
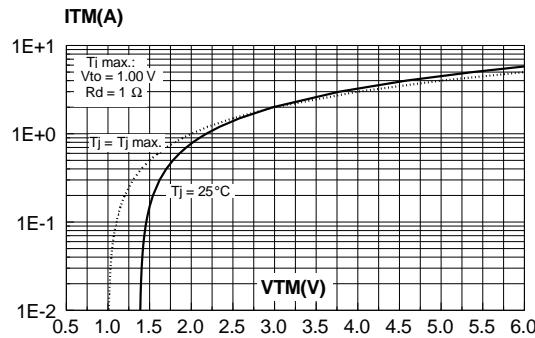


Fig. 10: On-state characteristics (maximum values).



P0102BL

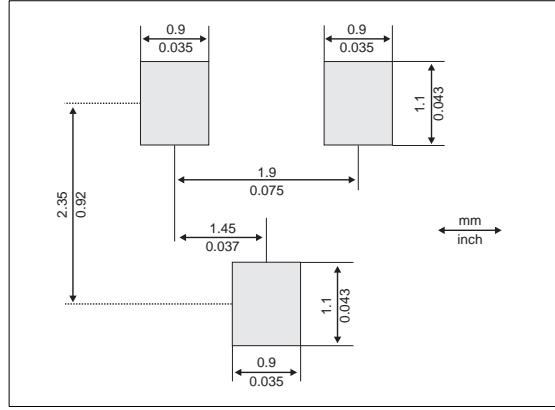
PACKAGE MECHANICAL DATA

SOT-23 (Plastic)

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.89	1.4	0.035	0.055
A1	0	0.1	0	0.004
B	0.3	0.51	0.012	0.02
c	0.085	0.18	0.003	0.007
D	2.75	3.04	0.108	0.12
e	0.85	1.05	0.033	0.041
e1	1.7	2.1	0.067	0.083
E	1.2	1.6	0.047	0.063
H	2.1	2.75	0.083	0.108
L	0.6 typ.		0.024 typ.	
S	0.35	0.65	0.014	0.026

FOOTPRINT DIMENSIONS (in millimeters)

SOT-23 (Plastic)



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